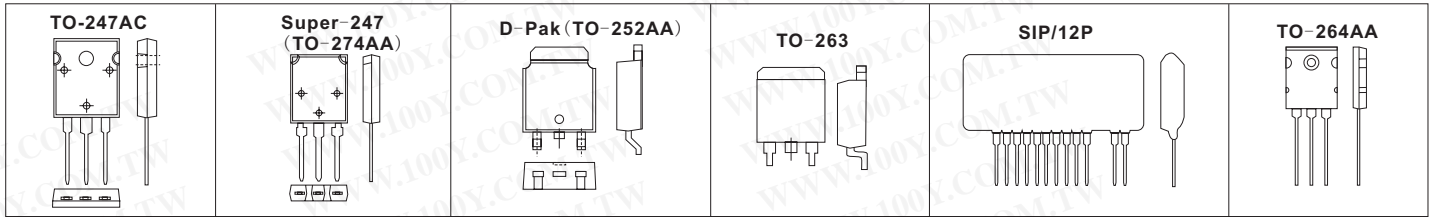


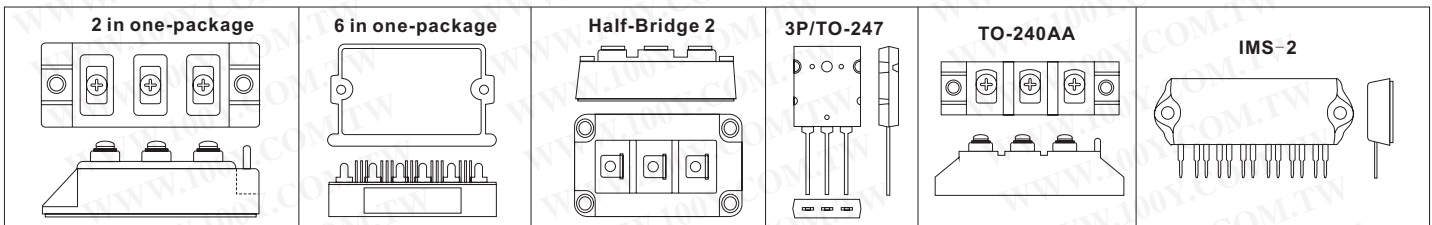
Semiconductors-Discretes

IGBT Discrete

Detailed product specifications are available on: us.100y.com.tw

Part No.	Product No.	Manufacturer	Description	Vces	Ic(A)	Pd(max)/W	Package
34295	IRG4PH50S	IR	Insulated gate bipolar transistor	1200V	33A	200 W	TO-247AC
34296	IRG4PH50U	IR	Insulated gate bipolar transistor	1200V	24A	200W	TO-247AC
34297	IRG4PH50UD	IR	Insulated gate bipolar transistor with ultrafast soft recovery diode	1200V	24A	200W	TO-247AC
34298	IRG4PSC71UD	IR	Insulated gate bipolar transistor with ultrafast soft recovery diode	600V	60A	350W	SUPER - 247
34299	IRG4PSH71K	IR	Insulated gate bipolar transistor	1200V	42A	350W	SUPER - 247
34300	IRG4RC10S	IR	Insulated gate bipolar transistor	600V	2.0A	38W	D-PAK (TO-252AA)
34301	IRG4RC20F	IR	Insulated gate bipolar transistor	600V	12A	66W	D-Pak (TO-252AA)
28944	IRGBC30M-S	IR	UltraFast CoPack IGBT	600V	16A	100W	3P/TO-263(SMD-220)
34428	IXSH40N60B	IXYS	High Speed IGBT	600V	75A	280W	TO-247 AD
40136	M5796L	MATSUSHITA	Hybrid ic for driving igbt modules	600V	20mA	2.38W	SIP/12P
35356	SGL60N90D	Fairchild	High Speed Switching Low Saturation Voltage High Input Impedance	900V	60A	200W	TO-264

IGBT Modules

Detailed product specifications are available on: us.100y.com.tw

Part No.	Product No.	Manufacturer	Description	Vces	Ic(A)	Pd(max)/W	Package
16523	2MBI100N-060	Fuji Elect	IGBT Module (2U)	600V	100A		
41842	2MBI100PC-140	Fuji Elect	IGBT MODULE (P-Series)	1400v	150A	780W	
41664	2MBI200N-060	Fuji Elect	IGBT Module	600V	200A	780W	2 in one-package
42919	2MBI300NK-060	Fuji Elect	IGBT Module	600V	300A	1100W	2 in one-package
42721	2MBI600NT-060	Fuji Elect	IGBT Module	600V	600A	2100W	2 in one-package
41989	2MBI75P-140	Fuji Elect	IGBT MODULE (P-Series)	1400V	75A	400W	
16519	6MBI15L-060	Fuji Elect	IGBT Module (6U)	600V	15A		
16627	6MBI30L-060	Fuji Elect	IGBT Module (6U)	600V	30A		
17294	6MBI8L-120	Fuji Elect	IGBT Module (6U)	1200V	8A		module
48537	6MBP30RH060	Fuji Elect	FUJI_IGBT-IPM	600V	30A	85W	6 in one-package
28980	BSM100GB120DN2	EUPEC	EUPEC-IGBT Power Module	1200V	150A	800	Half-Bridge 2
41033	BSM100GD120DN2	EUPEC	EUPEC-IGBT Power Module	1200V	150A		Half-Bridge 2
39642	BSM150GAL120DLC	EUPEC	62mm C-Serien Modul mit low loss IGBT2 und EmCon Diode	1200V	300A	1250W	
42977	BSM200GA120DN2	EUPEC	"EUPEC"_ IGBT	1200V	200A		
16520	BSM50GB120DN2	SIEMENS	IGBT power module (2U)	1200V	78A	400W	Half-bridge 1
42256	BSM50GB60DLC	EUPEC	IGBT-Modules	600V	50A		
37396	BSM50GD120DN2	SIEMENS	IGBT Power Module (Power module 3-phase full-bridge Including fast free-wheel diodes)	1200V	72A		ECONOPACK 2K
42250	BSM75GB60DLC	EUPEC	IGBT-Modules	600V	100A		
39897	CM200DU-24H	MATSUSHITA	IGBT Module	1200V	200A	1130W	
40884	CM200DY-24H	MATSUSHITA	IGBT Module	1200V	200A	1130W	
42823	CM75DY-12H	MITSUBISHI	High power switching useinsulated type	600V	75		IGBT
16521	CM75DY-24H	MITSUBISHI	Dual IGBT Module (2U)	1200V	75A		
43687	CPV363M4F	IR	IGBT SIP MODULE	600	16	36	IMS-2
32927	CPV363M4K	IR	IGBT SIP MODULE	600 V	6.0-11A	36W	IMS-2 Package Outline (13 Pins)
32929	CPV364M4K	IR	IGBT SIP MODULE	600V	24A	63W	IMS-2 Package Outline (13 Pins)
33129	FM2G300US60	Fairchild	Molding Type Module	600V	300A	1250W	7PM-BB
39423	IRGP30B120KD-E	IR		300V	30A	300W	TO-247AC
27244	MCD44-16Io8B	IXYS	"IXYS"Thyristor/Diode Modules	1600V	51A	10W	TO-240AA
35371	MG100J2YS50	TOSHIBA	N channel igbt (high pwer switching, motor control applications)	600V	100A	450W	
35375	MG100Q2YS51	TOSHIBA	N channel igbt (high pwer switching, motor control applications)	1200V	150A	660W	
38408	MG300Q1US11	TOSHIBA	silicon N channel IGBT	1200V	300A	2000W	
35377	MG50Q2YS50	TOSHIBA	N channel igbt (high power switching, motor control applications)	1200V	78A	400W	

